

Lecture 17: Photovoltaics

Course: MECH-422 – Power Plants

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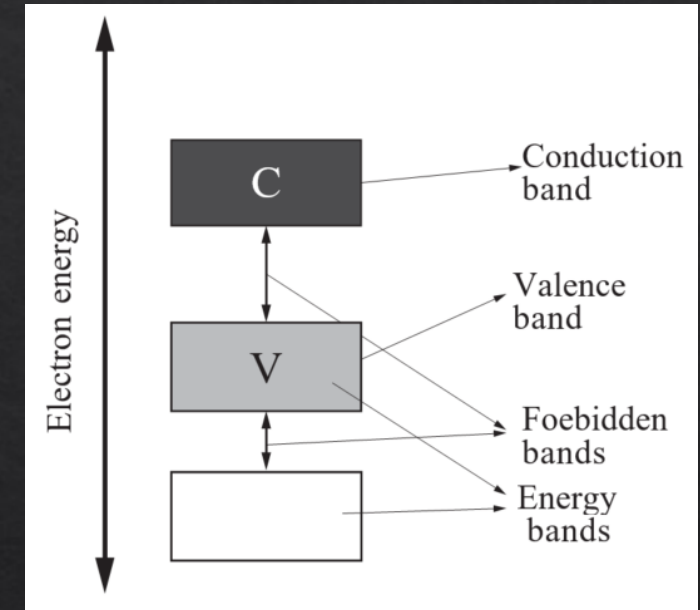
Term: Fall 2021

BUITEMS – DEPARTMENT OF MECHANICAL
ENGINEERING



Energy Bands

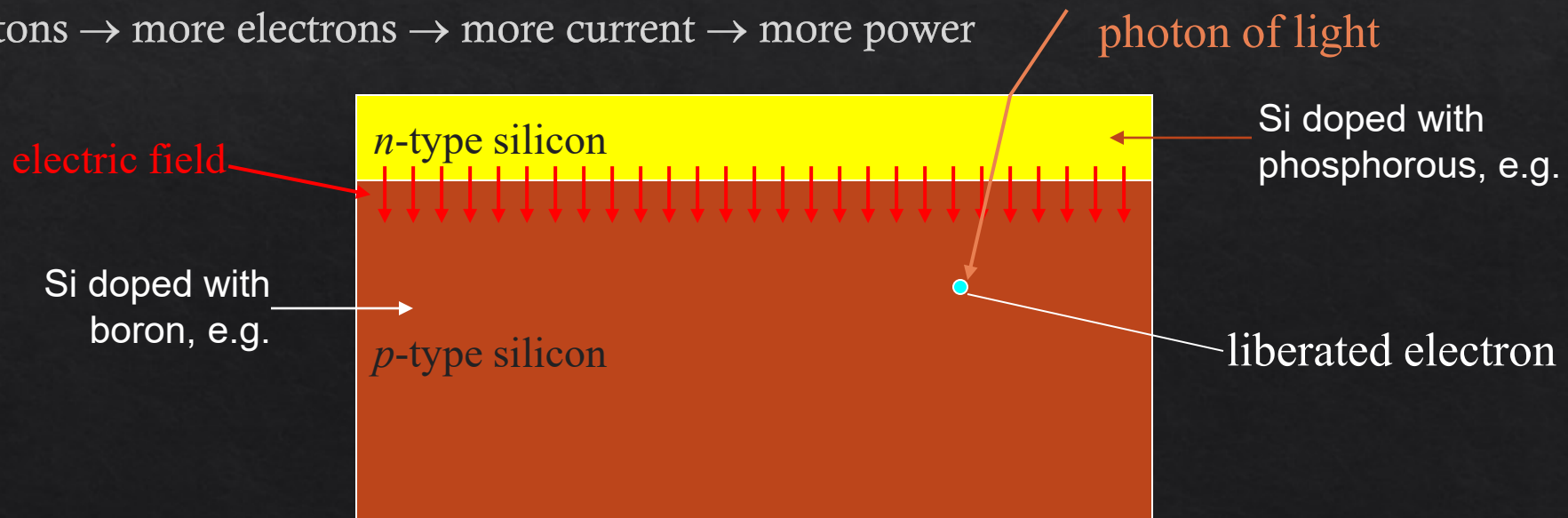
- It is proven that for a single atom, electrons can only occupy defined orbits with certain energy levels.
- These energy levels are expressed according to their energy in electron-volt (eV).
- Electrons can only “jump” from one energy level to a higher or lower energy level by absorbing or releasing a photon.
- The energy difference between the two energy levels must be equal to the energy of the absorbed or released photon.



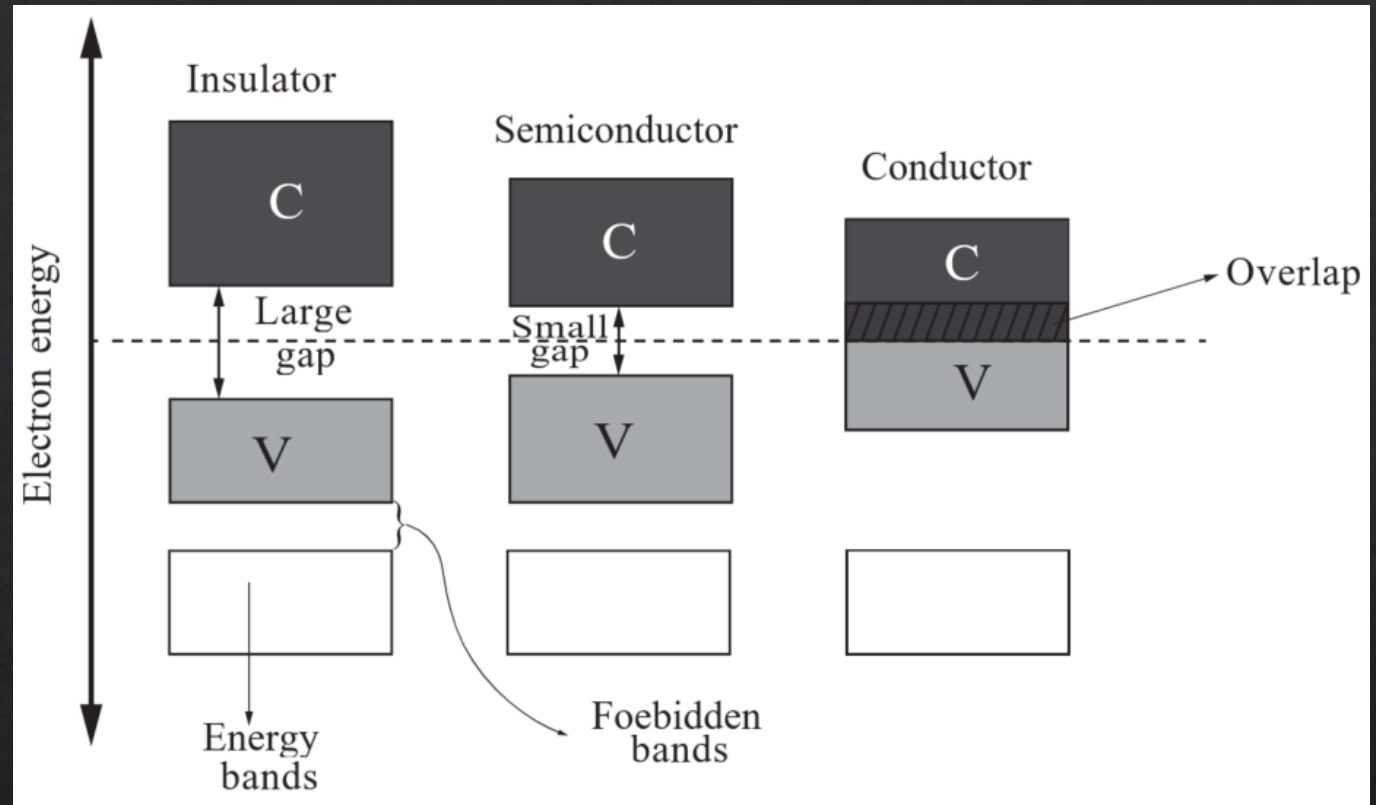
Electron energy levels in an atom

Photovoltaic (PV) Scheme

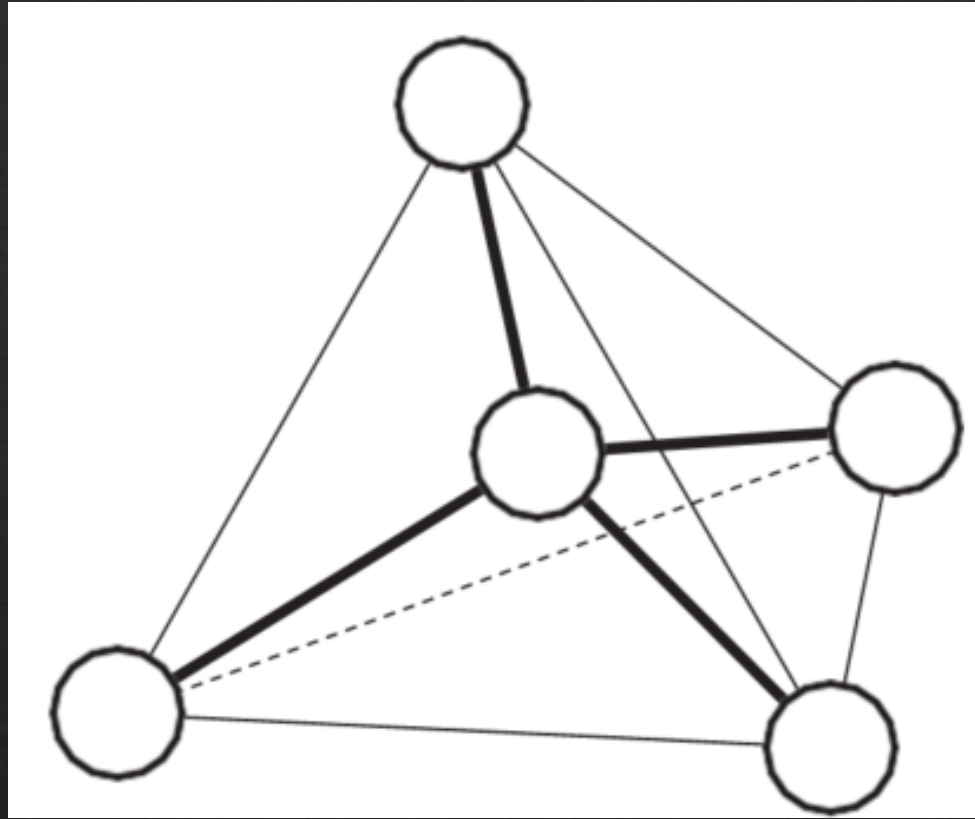
- ◇ Highly purified silicon (Si) from sand, quartz, etc. is “doped” with intentional impurities at controlled concentrations to produce a p-n junction
 - ◇ p-n junctions are common and useful: diodes, CCDs, photodiodes, transistors
- ◇ A photon incident on the p-n junction liberates an electron
 - ◇ photon disappears, any excess energy goes into kinetic energy of electron (heat)
 - ◇ electron wanders around drunkenly, and might stumble into “depletion region” where electric field exists (electrons, being negative, move *against* field arrows)
 - ◇ electric field sweeps electron across the junction, constituting a current
 - ◇ more photons → more electrons → more current → more power



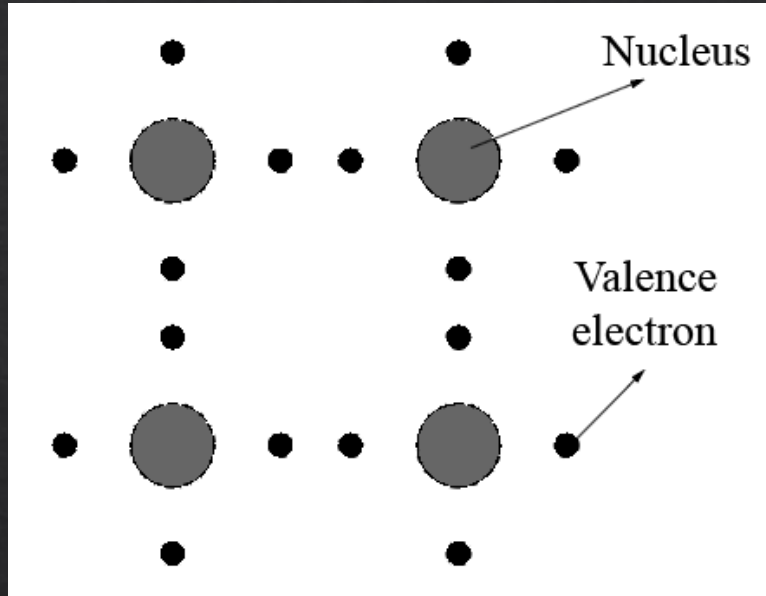
The **band gap** for some semiconductors that are used in the manufacturing of **solar cells** at the room temperature is as follows: **silicon 1.1 eV**, germanium 0.7 eV, gallium arsenide 1.4 eV, and cadmium telluride 1.4eV



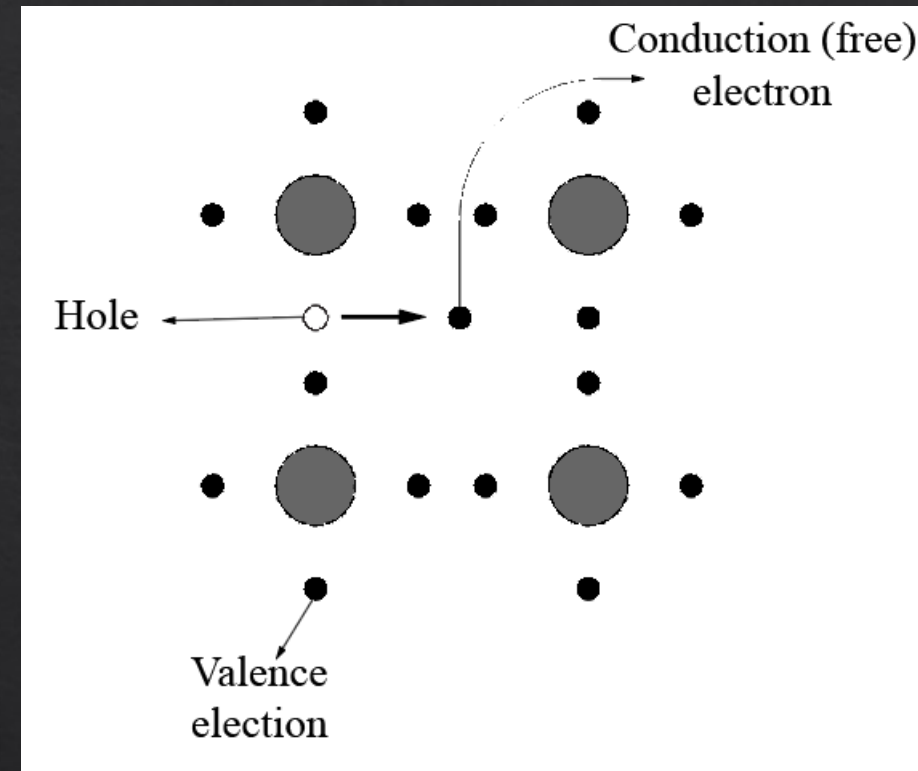
Band gap for conductors, semiconductors, and insulators



Atomic structure of silicon crystalline: three-dimensional structure with no electron promoted to conduction band

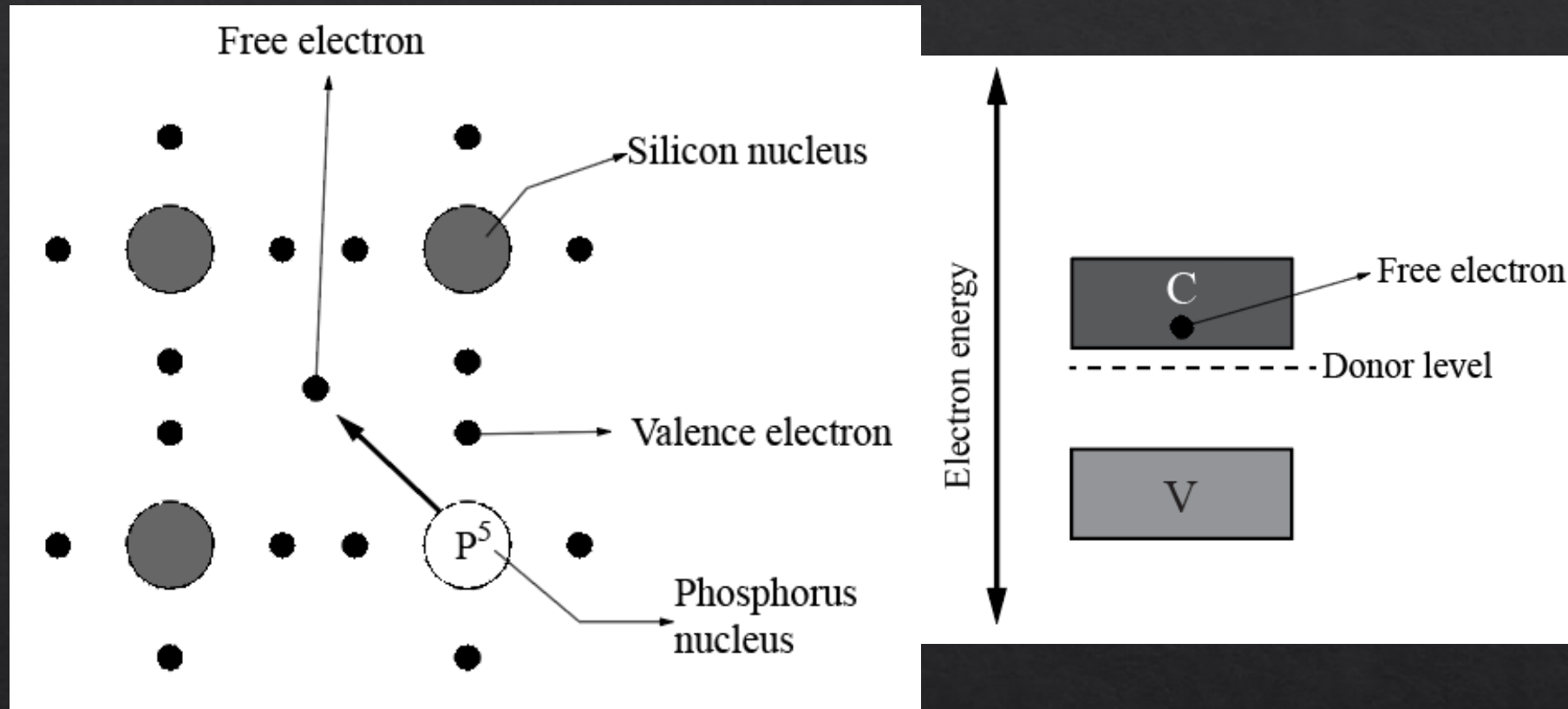


a

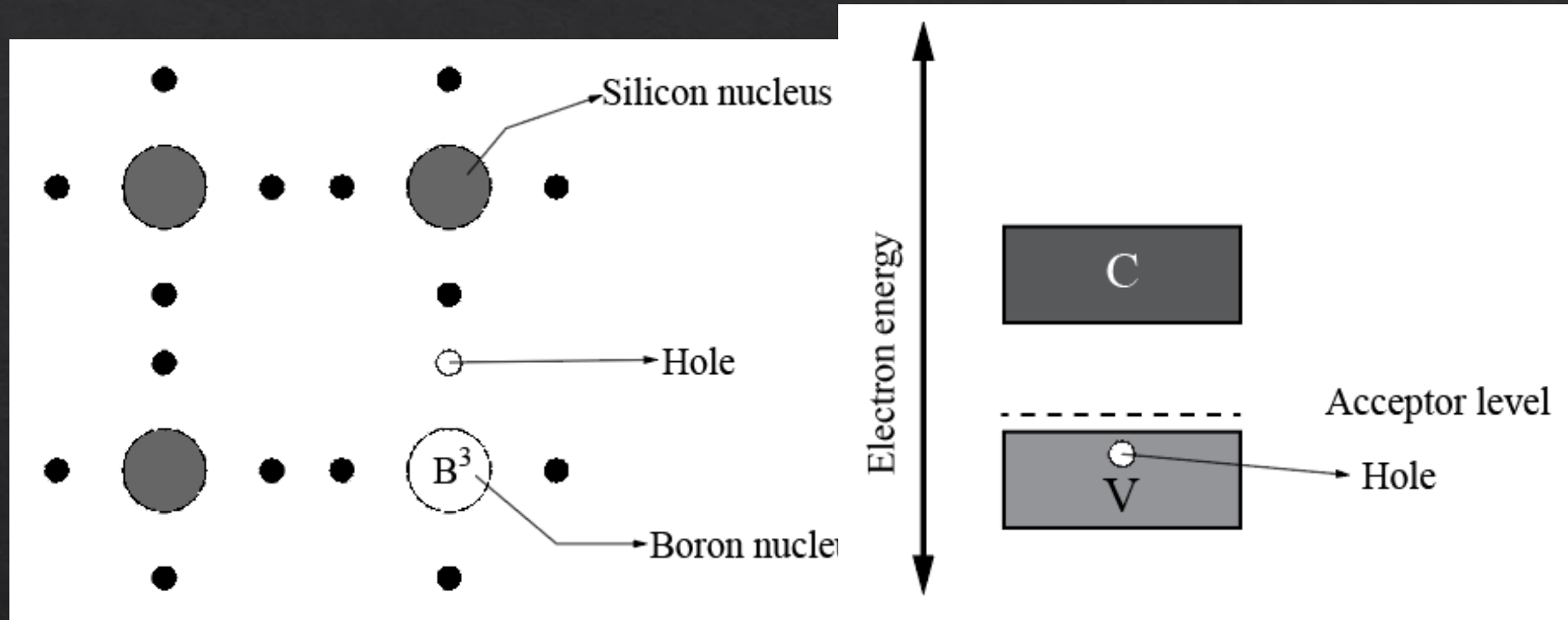


b

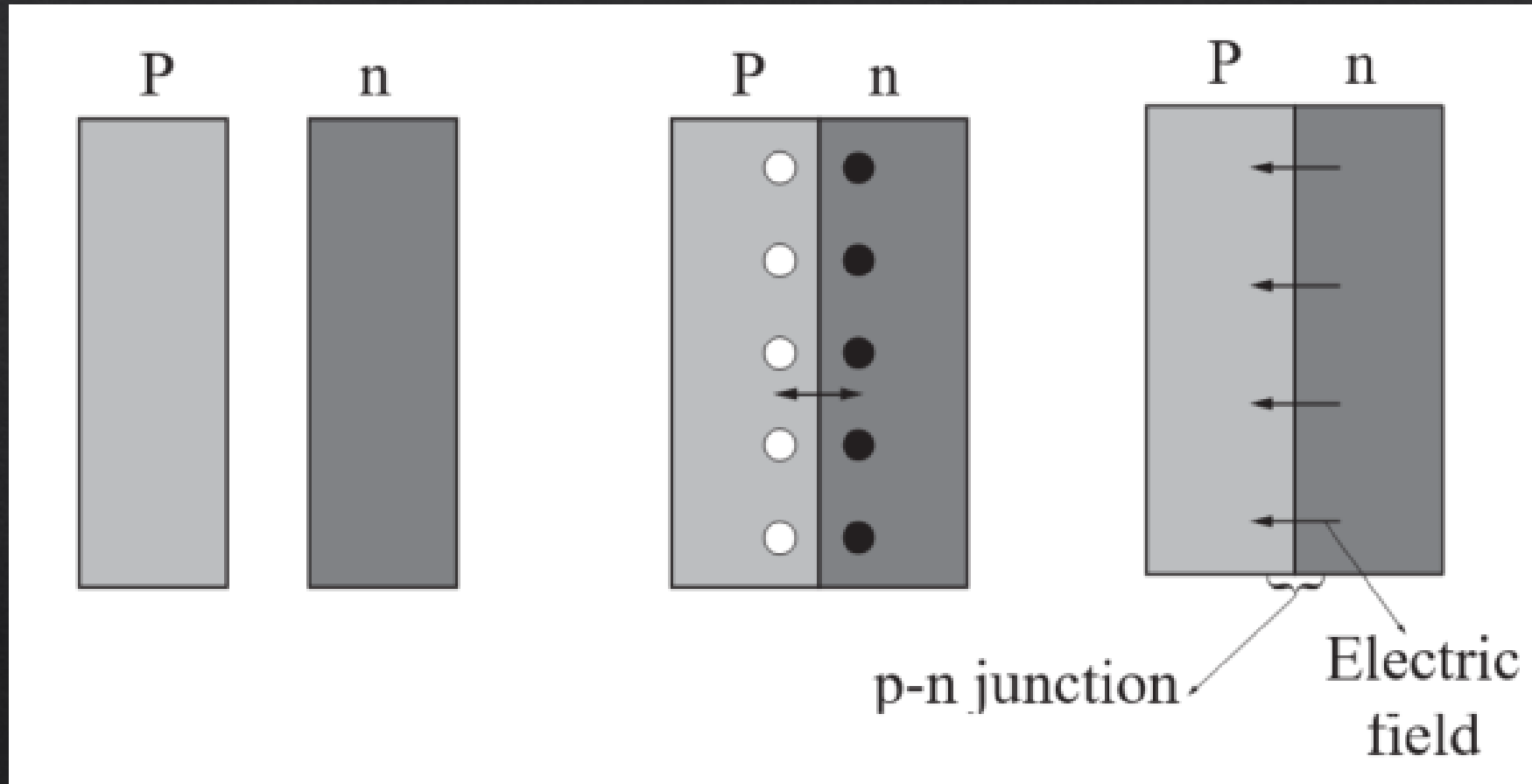
Atomic structure of silicon crystalline: a) simplified two-dimensional representation with no promoted electron b) simplified two-dimensional representation with one electron promoted to conduction band



Doping silicon crystalline with phosphorus to create an n-type semiconductor



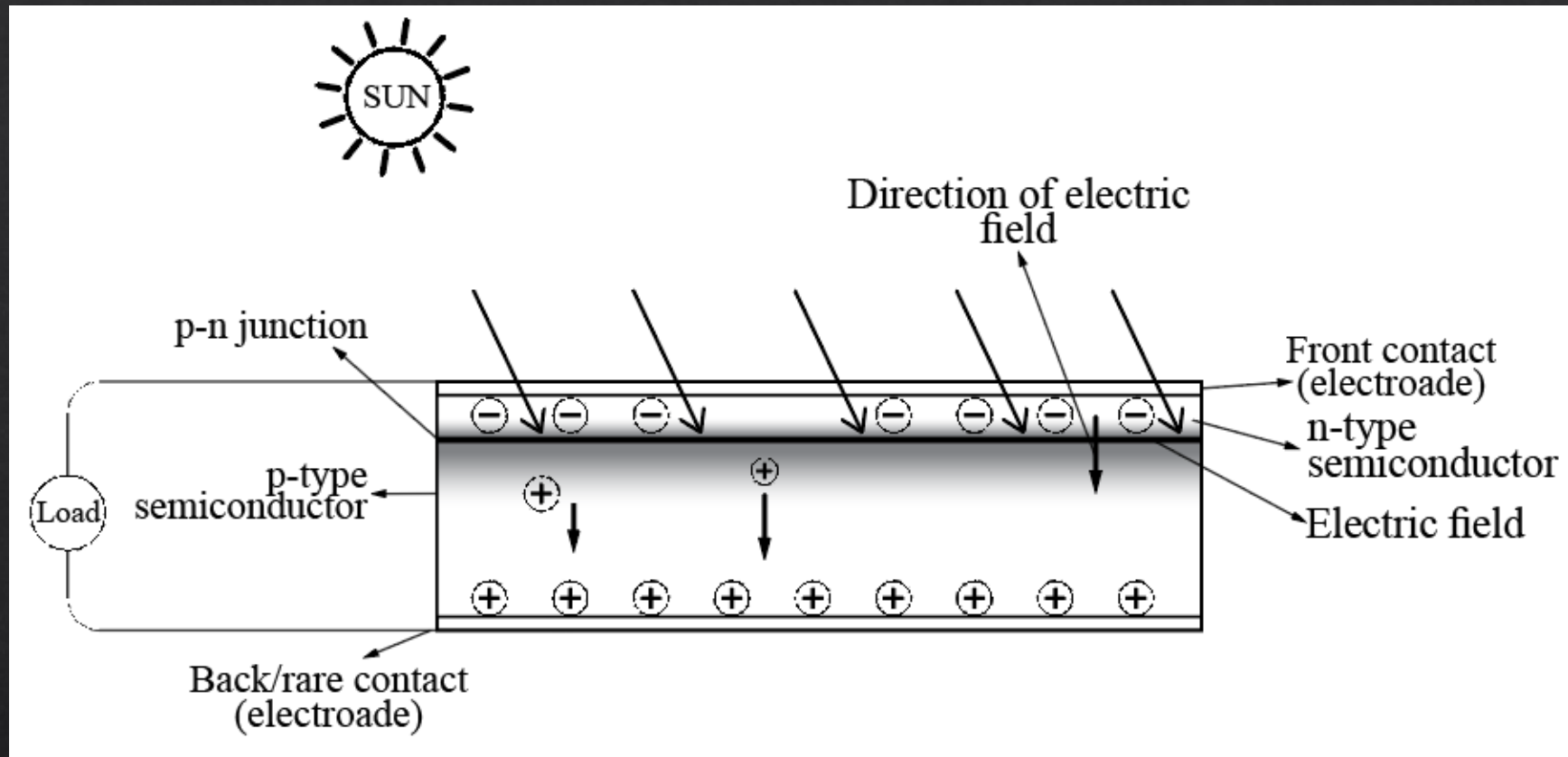
Doping silicon crystalline with boron to create a p-type semiconductor



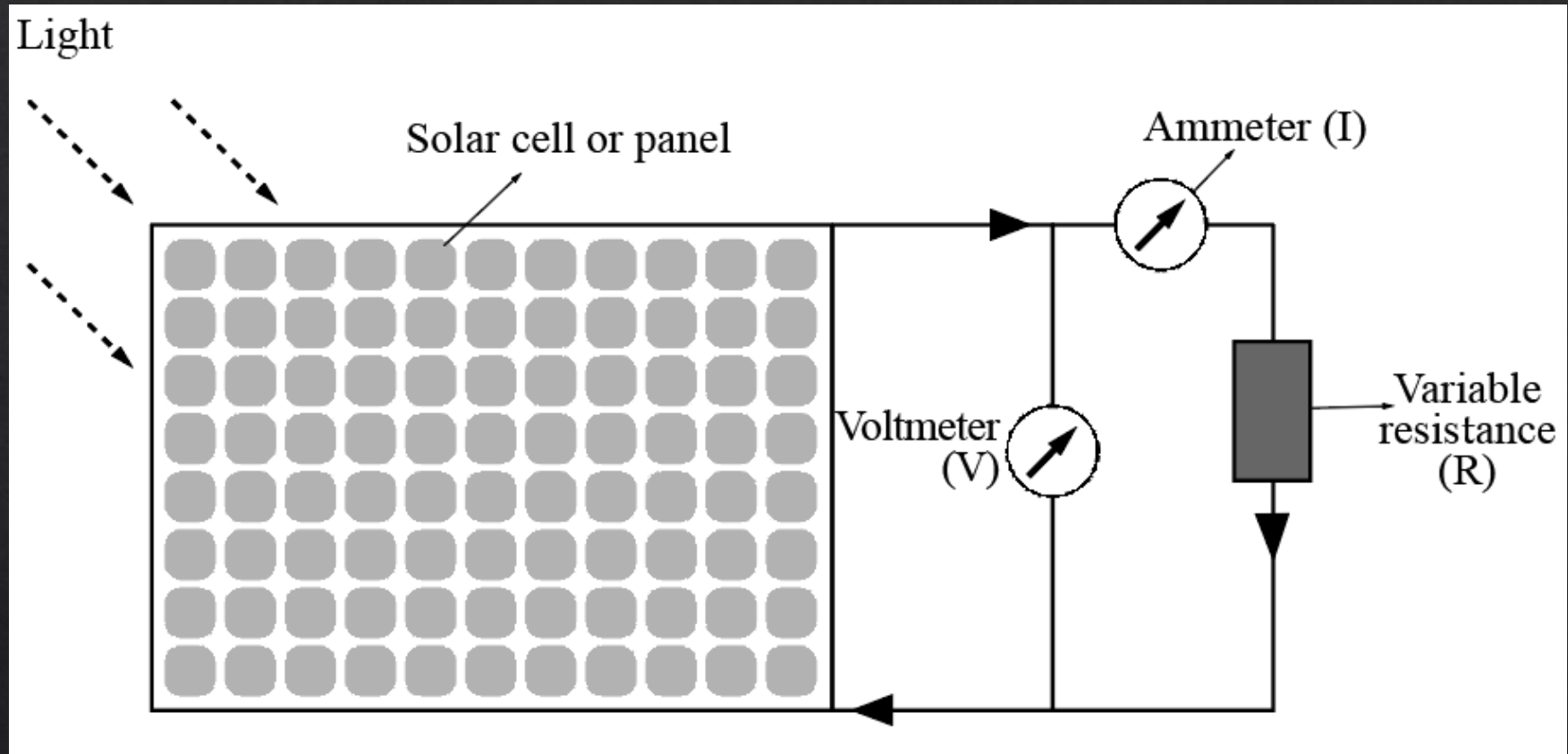
Schematic of a p-n junction to separate electrons and holes in electron-hole pairs



<https://www.youtube.com/watch?v=xKxrkht7CpY>



Schematic of what happens when sunlight strikes the surface of a solar cell



Schematic of a setup to create a characteristic curve (I-V curve) of a solar cell by varying the load's resistance and measuring current and voltage

Photon Energy

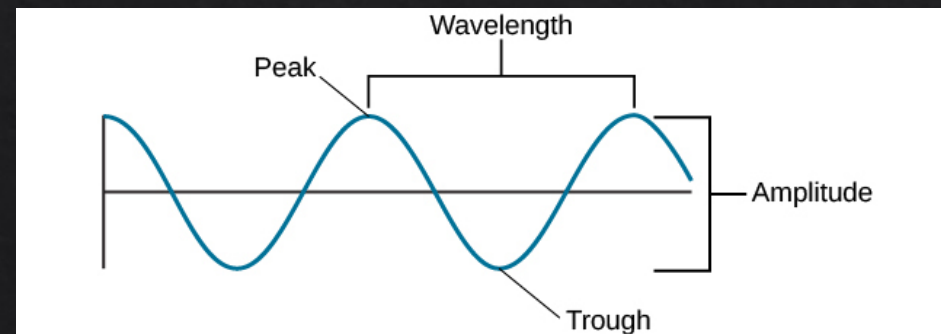
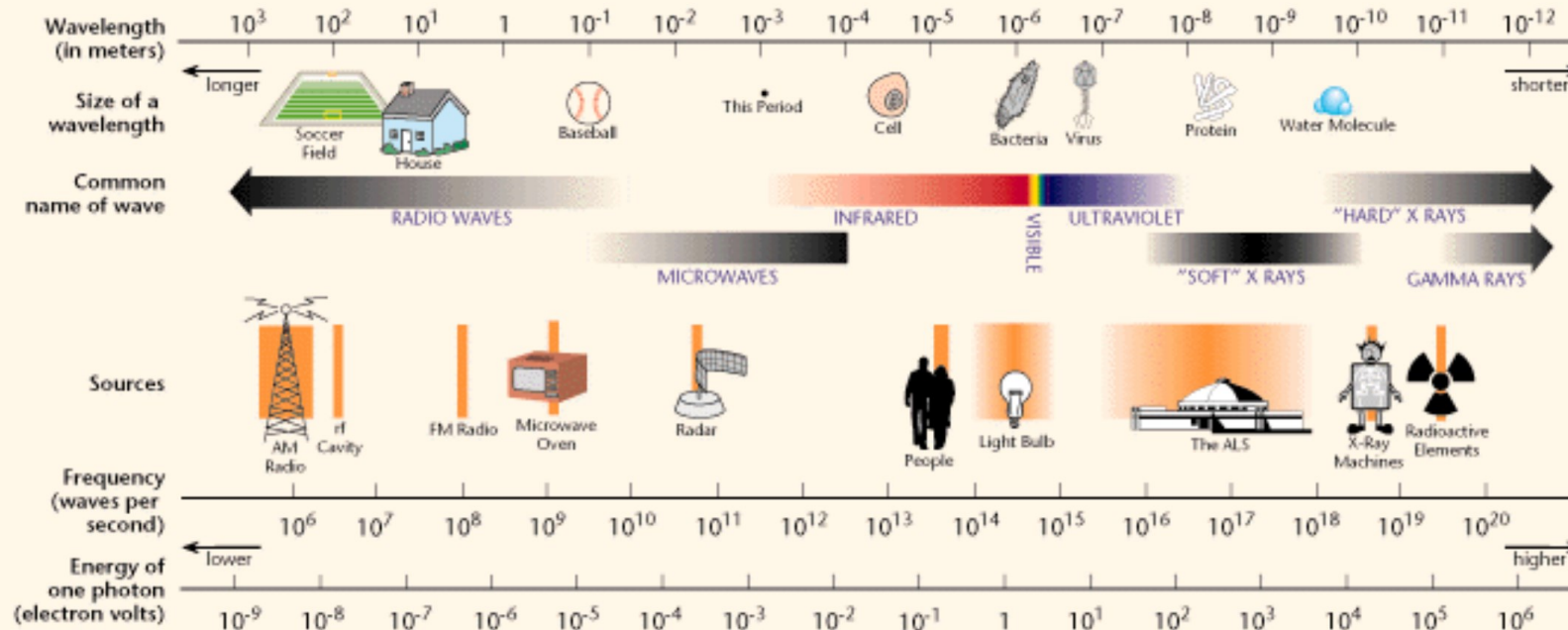
The photon energy, typically between 1 and 3.5 eV, is inversely proportional to its wavelength (or directly proportional to its frequency).

The energy of a photon as a function of its frequency and wavelength can be determined by the following equation:

$$E = h\nu = hc/\lambda \quad (11.5)$$

where E is energy of the photon (J), h is the Planck constant ($h = 6.626 \times 10^{-34}$ Js), ν and λ are the frequency (Hz) and wavelength of the photon (m), respectively, and c is the light speed $c = 2.998 \times 10^8$ m/s.

THE ELECTROMAGNETIC SPECTRUM



Example 11.8

We know that the wavelength of solar radiation spectrum on Earth ranges from about 300nm to about 2500nm. For the light with the wavelength of 300, 1130, and 2500nm,

- a. determine the photon energy of the part of solar radiation with the above wavelength in J and eV.
- b. determine the number of photons per second in each case if the light energy that is 0.1 W.

If the light with the wavelength of 300, 1130, and 2500 nm strikes a solar cell made of crystalline silicon (with the band gap of 1.1 eV).

1. Find the wavelengths that can generate electrical power?
2. What is the maximum efficiency for each wavelength?

End of Lecture!